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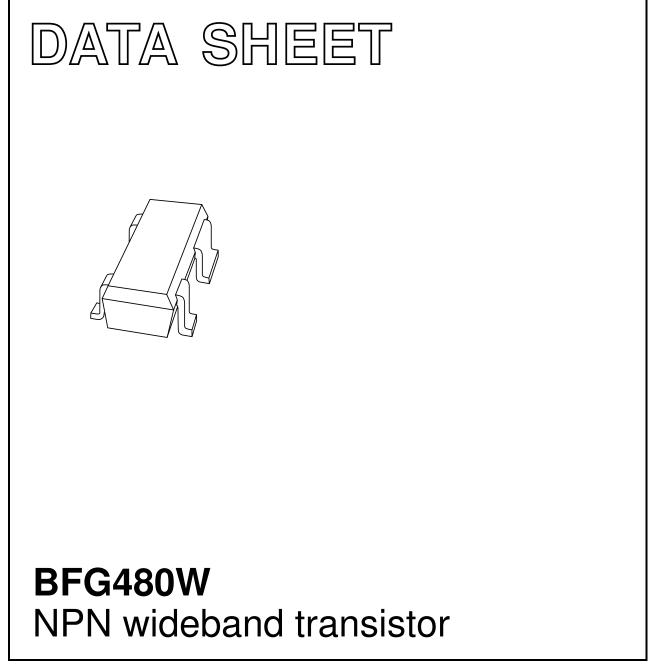


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DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1998 Jul 09

1998 Oct 21



FEATURES

- High power gain
- High efficiency
- Low noise figure
- High transition frequency
- Emitter is thermal lead
- Low feedback capacitance
- Linear and non-linear operation.

APPLICATIONS

- RF front end with high linearity system demands (CDMA)
- Common emitter class AB driver.

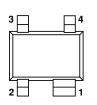
DESCRIPTION

NPN double polysilicon wideband transistor with buried layer for low voltage applications in a 4-pin dual-emitter SOT343R plastic package.

QUICK REFERENCE DATA

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	emitter
4	collector



Top view MSB842

Marking code: P6.

Fig.1 Simplified outline SOT343R.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	open base	-	4.5	V
I _C	collector current (DC)		80	250	mA
P _{tot}	total power dissipation	$T_s \le 60 \ ^{\circ}C$	-	360	mW
f _T	transition frequency	I_{C} = 80 mA; V_{CE} = 2 V; f = 2 GHz; T_{amb} = 25 °C	21	-	GHz
G _{max}	maximum gain	I_{C} = 80 mA; V_{CE} = 2 V; f = 2 GHz; T_{amb} = 25 °C	16	-	dB
F	noise figure	I_{C} = 8 mA; V_{CE} = 2 V; f = 2 GHz; Γ_{S} = Γ_{opt}	1.8	-	dB
G _p	power gain	Pulsed; class-AB; δ < 1 : 2; t _p = 5 ms; V _{CE} = 3.6 V; f = 2 GHz; P _L = 100 mW	13.5	-	dB
η _C	collector efficiency	Pulsed; class-AB; δ < 1 : 2; t _p = 5 ms; V _{CE} = 3.6 V; f = 2 GHz; P _L = 100 mW	45	-	%

CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

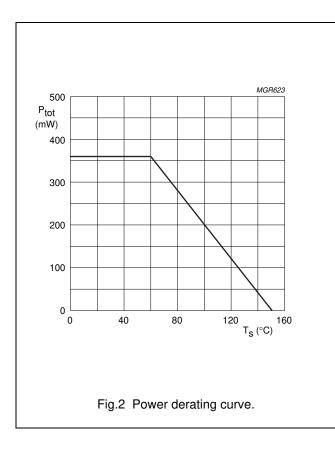
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	14.5	V
V _{CEO}	collector-emitter voltage	open base	-	4.5	V
V _{EBO}	emitter-base voltage	open collector	-	1	V
I _C	collector current (DC)		-	250	mA
P _{tot}	total power dissipation	$T_s \le 60 \text{ °C}$; note 1; see Fig.2	-	360	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	operating junction temperature		-	150	°C

Note

1. T_s is the temperature at the soldering point of the emitter pins.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	250	K/W



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CHARACTERISTICS

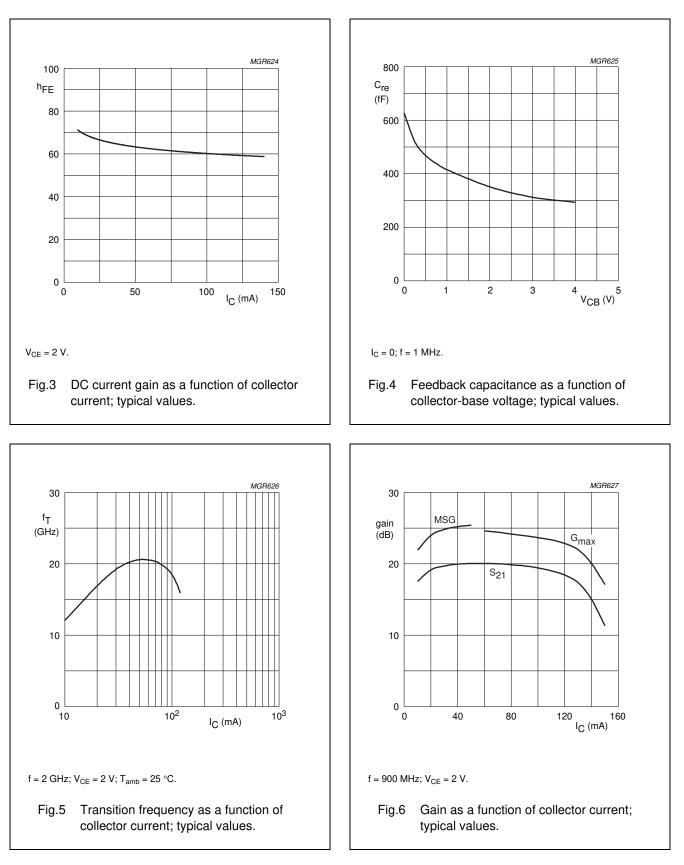
 T_j = 25 °C unless otherwise specified.

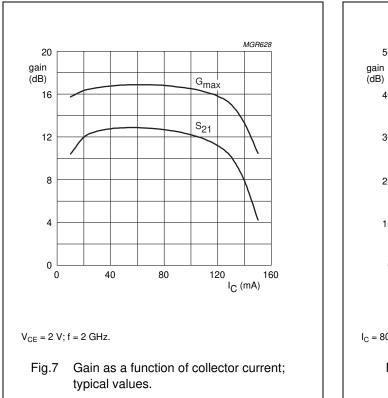
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)CBO}	collector-base breakdown voltage	$I_{\rm C} = 50 \ \mu {\rm A}; \ I_{\rm E} = 0$	14.5	-	_	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_{C} = 5 \text{ mA}; I_{B} = 0$	4.5	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = 100 \ \mu A; I_C = 0$	1	-	-	V
I _{CBO}	collector-base leakage current	$V_{CE} = 5 V; V_{BE} = 0$	-	-	70	nA
h _{FE}	DC current gain	$I_C = 80 \text{ mA}; V_{CE} = 2 \text{ V}; \text{see Fig.3}$	40	60	100	
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 2 V; f = 1 MHz$	-	1.4	-	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	-	2.2	-	pF
C _{re}	feedback capacitance	$I_C = 0$; $V_{CB} = 2$ V; f = 1 MHz; see Fig.4	-	340	-	fF
f _T	transition frequency	sition frequency $I_C = 80 \text{ mA}; V_{CE} = 2 \text{ V}; f = 2 \text{ GHz}; T_{amb} = 25 \text{ °C}; \text{ see Fig.5}$		21	-	GHz
G _{max}	maximum power gain; note 1	I_{C} = 80 mA; V_{CE} = 2 V; f = 2 GHz; T_{amb} = 25 °C; see Figs 7 and 8	-	16	-	dB
$ S_{21} ^2$	insertion power gain	$I_C = 80 \text{ mA}; V_{CE} = 2 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}; \text{ see Fig.8}$	-	12	-	dB
F	noise figure	$I_{C} = 8 \text{ mA}; V_{CE} = 2 \text{ V}; f = 900 \text{ MHz};$ $\Gamma_{S} = \Gamma_{opt}; \text{ see Fig.13}$	-	1.2	-	dB
		$I_C = 8 \text{ mA}; V_{CE} = 2 \text{ V}; f = 2 \text{ GHz};$ $\Gamma_S = \Gamma_{opt}; \text{ see Fig.13}$	-	1.8	-	dB
P _{L1}	output power at 1 dB gain compression	$\label{eq:class-AB; } \begin{split} &Class-AB \delta < 1:2; t_p = 5 \; \text{ms;} \\ &V_{CE} = 3.6 \; V; \; I_{CQ} = 1 \; \text{mA; } f = 2 \; GHz \end{split}$	-	20	-	dBm
ITO	third order intercept point	$I_{C} = 80 \text{ mA}; V_{CE} = 2 \text{ V}; f = 2 \text{ GHz};$ $Z_{S} = Z_{S \text{ opt}}; Z_{L} = Z_{L \text{ opt}}; \text{ note } 2$	-	28	-	dBm

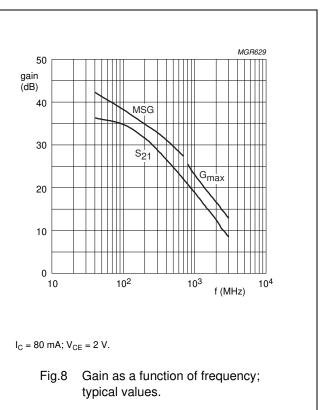
Notes

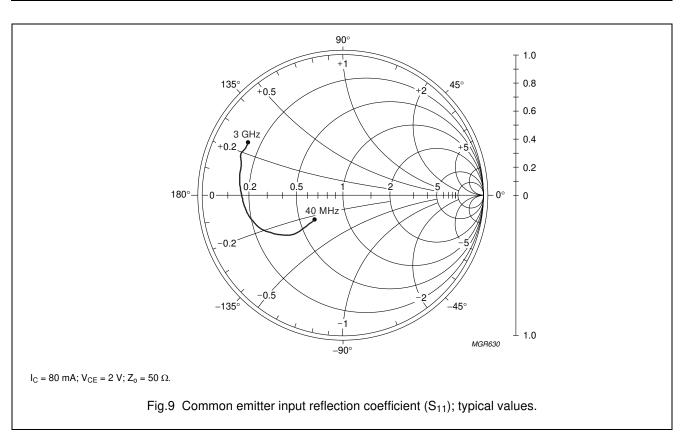
1. G_{max} is the maximum power gain, if K > 1. If K < 1 then G_{max} = MSG; see Figs 6, 7 and 8.

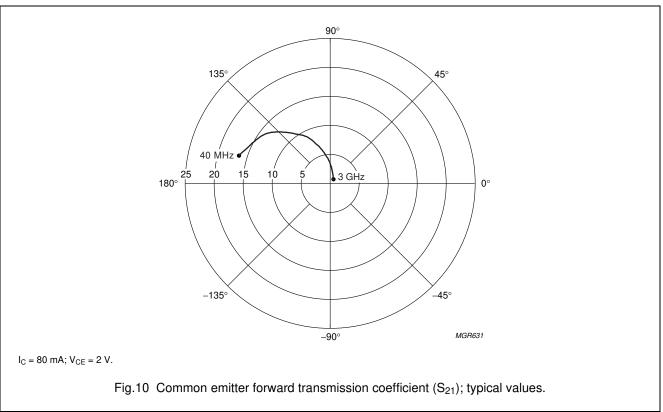
2. Z_S is optimized for noise; Z_L is optimized for gain.

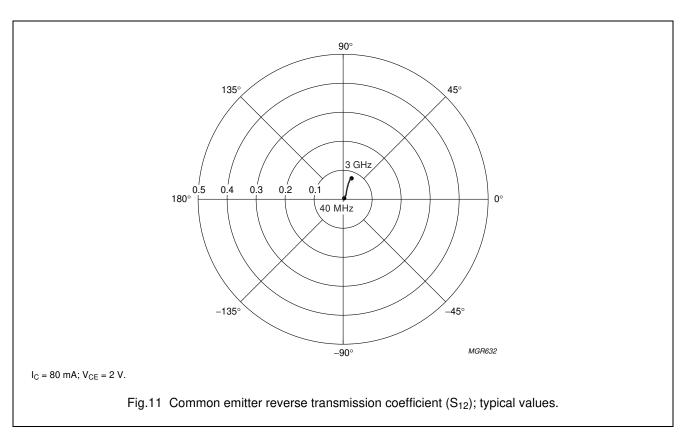


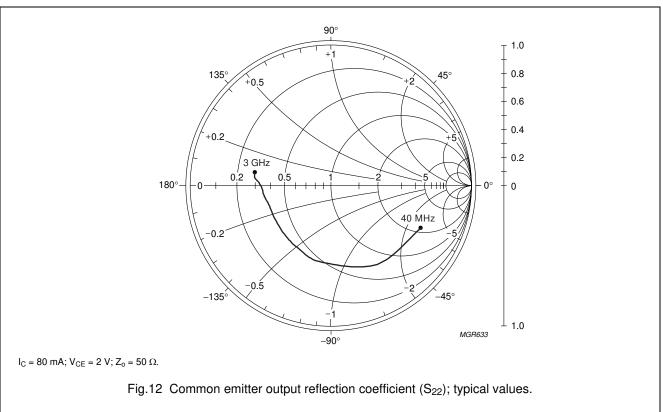










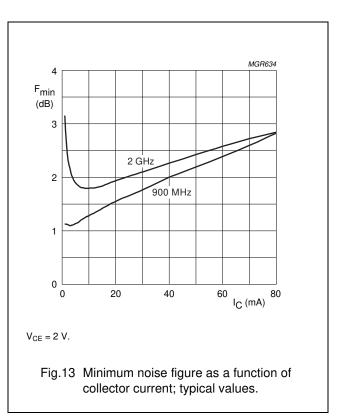


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Noise data

$V_{CE} =$	2 V	; typical	l values.
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f (MHz)	I _C (mA)	F _{min} (dB)	Γ_{mag}	Γ_{angle}	r n (Ω)
900	2	1.1	0.41	96.1	0.21
	4	1.1	0.31	106.6	0.14
	6	1.2	0.27	118.4	0.12
	8	1.2	0.26	131.7	0.10
	10	1.3	0.28	143.2	0.10
	20	1.6	0.39	166.2	0.07
	40	2.0	0.49	176.0	0.07
	60	2.3	0.57	179.5	0.07
	80	2.9	0.45	177.3	0.18
2000	2	2.4	0.57	171.9	0.09
	4	2.0	0.49	178.9	0.08
	6	1.8	0.46	-175.7	0.09
	8	1.8	0.44	-171.7	0.09
	10	1.8	0.43	-168.4	0.09
	12	1.8	0.44	-165.3	0.10
	14	1.8	0.44	-163.7	0.10
	20	1.9	0.46	-158.3	0.11
	40	2.3	0.52	-150.2	0.14
	60	2.6	0.56	-147.7	0.18
	80	2.8	0.60	-146.1	0.22

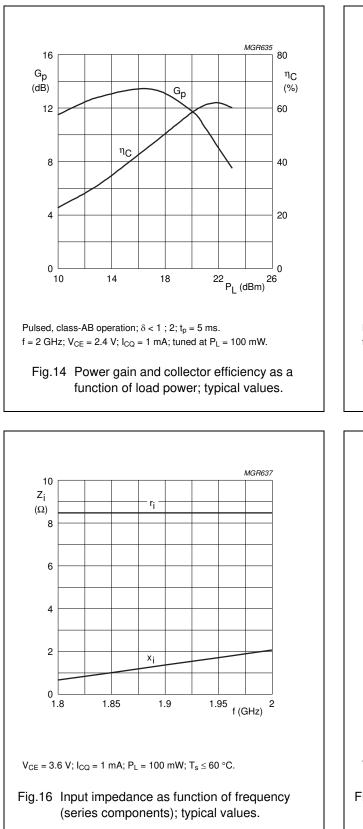


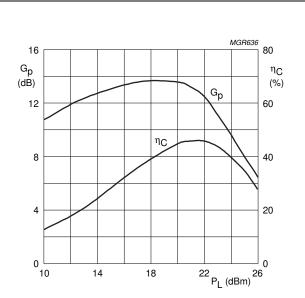
APPLICATION INFORMATION

RF performance at $T_s \leq 60\ ^\circ C$ in a common emitter test circuit (see Figs 18 and 19).

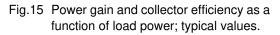
MODE OF OPERATION	f	V _{CE}	I _{CQ}	P _L	G _p	^η с
	(GHz)	(V)	(mA)	(mW)	(dB)	(%)
Pulsed; class-AB; $\delta < 1$: 2; $t_p = 5$ ms	2	3.6	1	100	typ. 13.5	typ. 45

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Pulsed, class-AB operation; δ < 1 ; 2; t_p = 5 ms. f = 2 GHz; V_{CE} = 3.6 V; I_{CQ} = 1 mA; tuned at P_L = 100 mW.



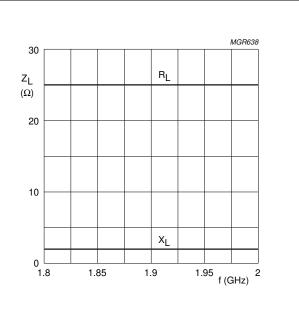
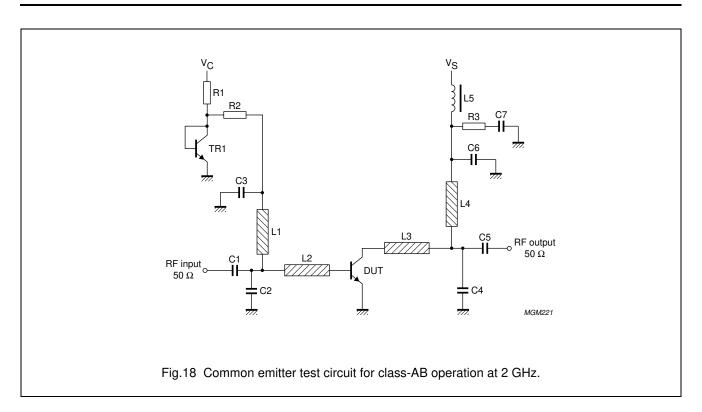




Fig.17 Load impedance as a function of frequency (series components); typical values.

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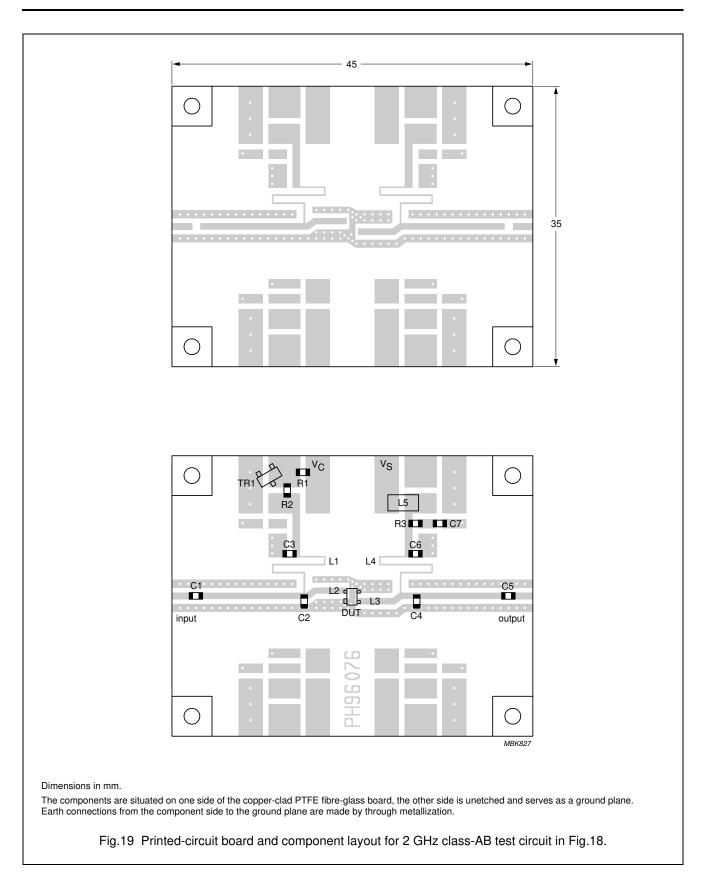


List of components used in test circuit (see Figs 18 and 19)

COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE No.
C1, C5	multilayer ceramic chip capacitor; note 1	24 pF		
C2, C4	multilayer ceramic chip capacitor; note 1	2 pF		
C3, C6	multilayer ceramic chip capacitor, note 1	15 pF		
C7	multilayer ceramic chip capacitor; note 1	1 nF		
L1, L4	stripline; note 2		18 x 0.2 mm	
L2	stripline; note 2	50 Ω	5 x 0.8 mm	
L3	stripline; note 2	50 Ω	6 x 0.8 mm	
L5	Grade 4S2 Ferroxcube chip bead			4330 030 36300
R1	metal film resistor	220 Ω; 0.4 W		
R2, R3	metal film resistor	10 Ω; 0.4 W		
TR1	NPN transistor	BC817		9335 895 20215

Notes

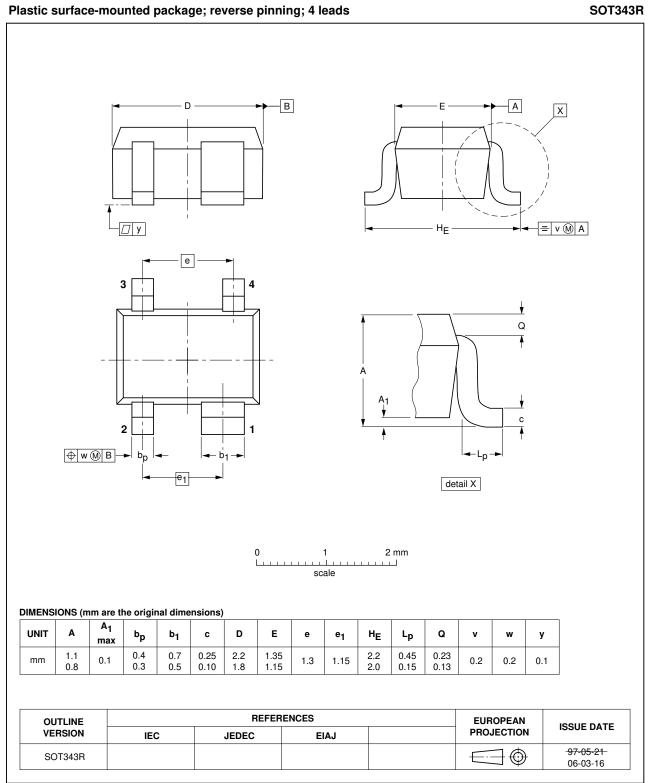
- 1. American Technical Ceramics type 100A or capacitor of same quality.
- 2. The striplines are on a double copper-clad printed-circuit board with PTFE fibre-glass dielectric ($\epsilon_r = 6.15$, tan $\delta = 0.0019$); thickness 0.64 mm, copper cladding = 35 μ m.



BFG480W

NPN wideband transistor

PACKAGE OUTLINE



BFG480W

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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